



	<p>SI1551DL-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI1551DL-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N/P-CH 20V SC70-6</p> <p>Datenblätter:  SI1551DL-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23585 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1551DL-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N/P-CH 20V SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23585 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	270mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	290mA, 410mA
Rds On (Max) @ Id, Vgs	1.9 Ohm @ 290mA, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)

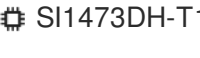
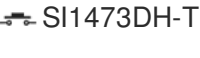
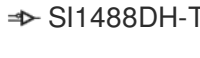
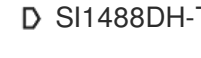
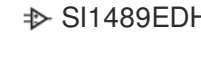
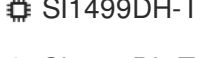
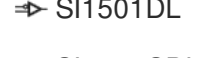
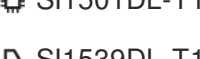
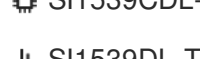
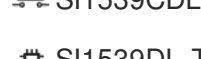
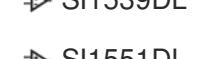
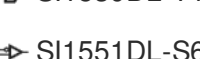

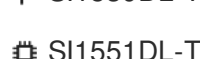
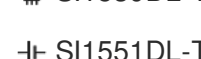
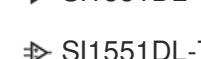

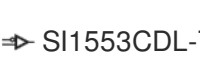
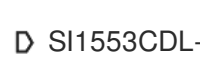
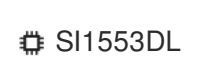
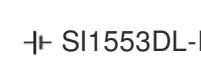


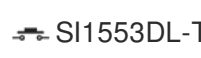
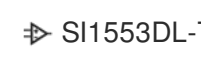
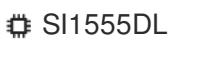
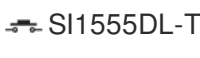
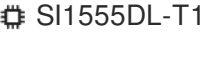
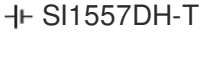

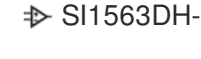
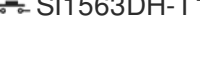
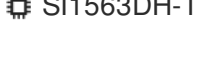
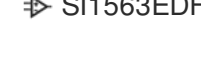



SI1551DL-T1-GE3 ist neu im Original. Suche SI1551DL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1551DL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1551DL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1552AI-JE-DCC-32.768D SiTime SI1552AI-JE-DCC-32.768D SITIME</p>	 <p>SI1551DL-E3 VISHAY VISHAY SOT363</p>	 <p>SI1551DL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SC70-6</p>	 <p>SI1553CDL-T1-GE3 Vishay / Siliconix MOSFET N/P-CH 20V SC70-6</p>
 <p>SI1551DL-S6-E3 VISHAY SI1551DL-S6-E3 VISHAY</p>	 <p>SI1553CDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SC70-6</p>	 <p>SI1551DL-T1-E3 Vishay / Siliconix MOSFET N/P-CH 20V SC70-6</p>	 <p>SI1551DL-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SC70-6</p>

heiße Teile

Mehr

 SI1473DH-T1-GE3	 SI1473DH-T1-GE3	 SI1488DH-T1-GE3	 SI1488DH-T1-GE3	 SI1489EDH-T1-GE3
 SI1489EDH-T1-GE3	 SI1499DH-T1-GE3	 SI1499DH-T1-GE3	 SI1501DL	 SI1501DL-T1
 SI1501DL-T1-E3	 SI1501DL-T1-GE3	 SI1539CDL-T1-GE3	 SI1539CDL-T1-GE3	 SI1539DL
 SI1539DL-T1-E3	 SI1539DL-T1-E3	 SI1539DL-T1-GE3	 SI1539DL-T1-GE3	 SI1551DL
 SI1551DL-S6-E3	 SI1551DL-T1	 SI1551DL-T1-E3	 SI1551DL-T1-E3	 SI1551DL-T1-GE3
 SI1552AI-JE-DCC-32.768D	 SI1553CDL-T1-GE3	 SI1553CDL-T1-GE3	 SI1553DL	 SI1553DL-F1
 SI1553DL-T1	 SI1553DL-T1	 SI1553DL-T1-E3	 SI1553DL-T1-E3	 SI1553DL-T1-GE3
 SI1553DL-T1-GE3	 SI1555DL	 SI1555DL-T1	 SI1555DL-T1-E3	 SI1555DL-T1-E3
 SI1555DL-T1-GE3	 SI1557DH-T1-E3	 SI1557DH-T1-E3	 SI1557DH-T1-GE3	 SI15563DH-T1-E3
 SI1563DH-T1-E3	 SI1563DH-T1-GE3	 SI1563DH-T1-GE3	 SI1563EDH-T1-GE3	 SI1563EDH-T1-GE3

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